DISCRETE SEMICONDUCTORS

DATA SHEET

BYV40E seriesRectifier diodes ultrafast, rugged

Product specification

September 2018



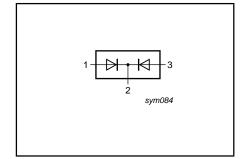
Rectifier diodes ultrafast, rugged

BYV40E series

FEATURES

- · Low forward volt drop
- · Fast switching
- · Soft recovery characteristic
- · Reverse surge capability
- · High thermal cycling performance
- low profile surface mounting package

SYMBOL



QUICK REFERENCE DATA

$$V_R = 150 \text{ V}/200 \text{ V}$$

$$V_F \le 0.7 \text{ V}$$

$$I_{O(AV)} = 1.5 \text{ A}$$

$$I_{RRM} = 0.1 \text{ A}$$

$$t_{rr} \le 25 \text{ ns}$$

GENERAL DESCRIPTION

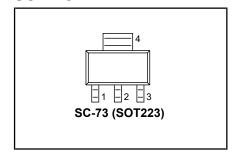
Dual, common cathode, ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV40E series is supplied in the SOT223 surface mounting package.

PINNING

IN DESCRIPTION	
anode 1	
cathode	
anode 2	
cathode	

SOT223



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	ER CONDITIONS MIN. MAX.		λX.	UNIT	
V _{RRM} V _{RWM} V _R	Peak repetitive reverse voltage Crest working reverse voltage Continuous reverse voltage	$\label{eq:total_bound} \textbf{BYV40E}$ $\label{eq:total_constraint} T_{sp} \leq 120^{\circ}\text{C}$	1 1 1	-150 150 150 150	-200 200 200 200	V V V
I _{O(AV)}	Average rectified output current (both diodes conducting) ¹ Repetitive peak forward current	$T_{sp} \le 132^{\circ}C$ $t = 25 \ \mu s; \ \delta = 0.5;$	-		.5 .5	A A
I _{FSM}	per diode Non-repetitive peak forward current per diode	$T_{sp} \le 132$ °C $t_p = 10$ ms $t_p = 8.3$ ms $t_p = 8.3$ ms $t_p = 8.3$ ms $t_p = 150$ °C prior $t_p = 150$ °C prior $t_p = 150$ °C prior	-		6 .6	A A
I _{RRM}	Repetitive peak reverse current per diode	$t_p = 2 \mu s; \delta = 0.001$	-	0	.1	Α
I _{RSM}	Non-repetitive peak reverse current per diode	t _p = 100 μs	-	0	.1	Α
T _{stg} T _j	Storage temperature Operating junction temperature		-65 -		50 50	°C

¹ Neglecting switching and reverse current losses

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ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _C	Electrostatic discharge capacitor voltage	Human body model; C = 250 pF; R = 1.5 kΩ	1	8	kV

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-sp}	Thermal resistance junction to solder point	one or both diodes conducting	1	-	15	K/W
R _{th j-a}	Thermal resistance	pcb mounted; minimum footprint pcb mounted; pad area as in fig:11	-	156 70	-	K/W K/W

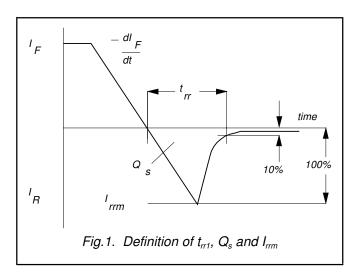
ELECTRICAL CHARACTERISTICS

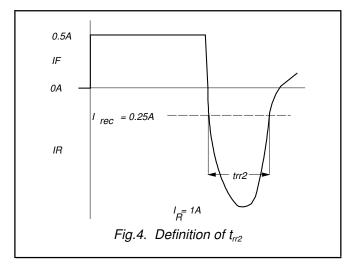
characteristics are per diode at T_i = 25 °C unless otherwise stated

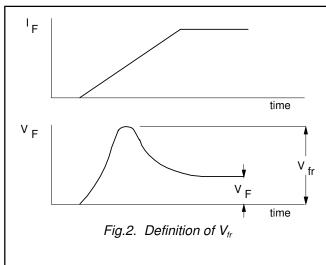
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	$I_F = 0.5 \text{ A}; T_i = 150^{\circ}\text{C}$	-	0.50	0.7	V
1.	_	I _E = 1.5 A _	-	0.82	1.0	V
l _R	Reverse current	$\dot{V}_{R} = V_{RWM}$; $T_{j} = 100 ^{\circ}C$	-	100	300	μA
		$V_R = V_{RWM}$	-	5	10	μA
Q_s	Reverse recovery charge	$I_F = 2 \text{ A}; V_R \ge 30 \text{ V}; -dI_F/dt = 20 \text{ A}/\mu\text{s}$	-	-	11	'nC
t _{rr1}	Reverse recovery time	$I_{F} = 1 \text{ A}; V_{R} \ge 30 \text{ V};$	-	-	25	ns
		$-dI_F/dt = 100 A/\mu s$				
t _{rr2}	Reverse recovery time	$I_F = 0.5 \text{ A to } I_R = 1 \text{ A}; I_{rec} = 0.25 \text{ A}$	-	10	20	ns
$V_{\rm fr}$	Forward recovery voltage	$I_F = 2 \text{ A}; dI_F/dt = 20 \text{ A/µs}$	-	3	-	V

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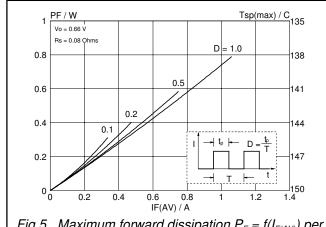
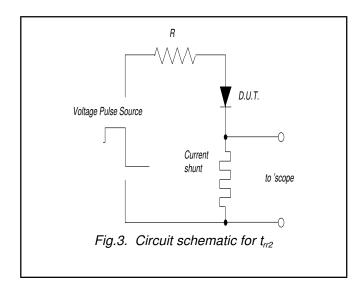


Fig.5. Maximum forward dissipation $P_F = f(I_{F(AV)})$ per diode; square current waveform where $I_{F(AV)} = I_{F(RMS)} \ x \ \sqrt{D}$.



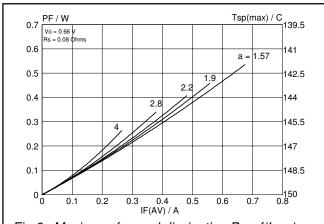
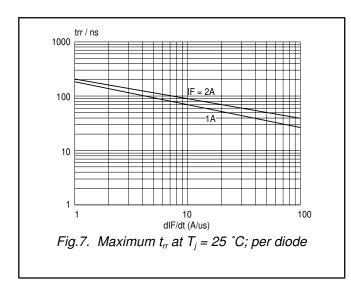


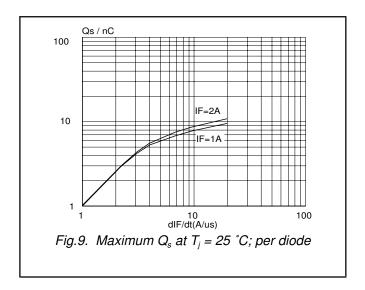
Fig.6. Maximum forward dissipation $P_F = f(I_{F(AV)})$ per diode; sinusoidal current waveform where a = form factor = $I_{F(RMS)} / I_{F(AV)}$.

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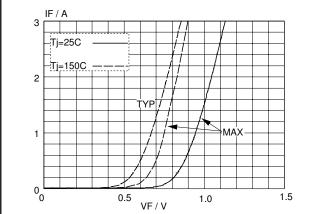


Fig.8. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

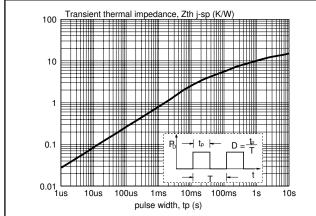


Fig.10. Transient thermal impedance; per diode; $Z_{th j\text{-sp}} = f(t_p)$.

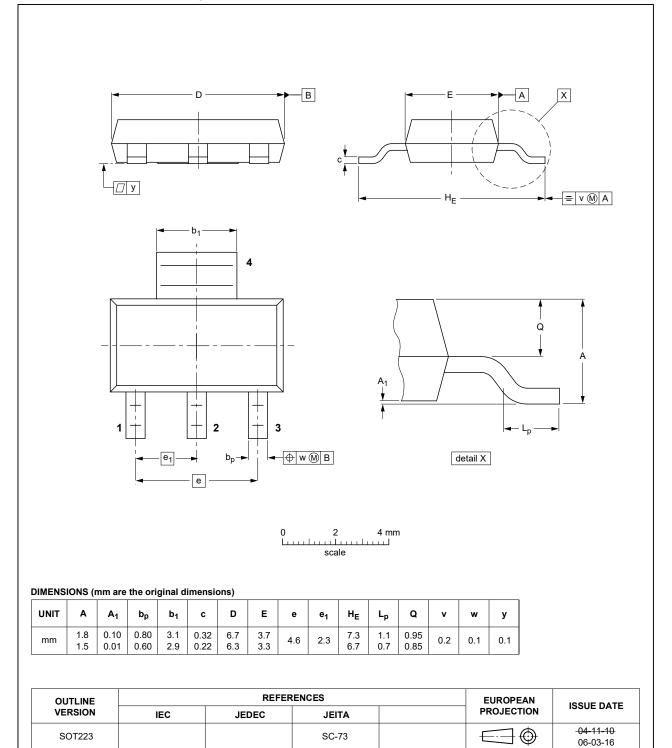
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MECHANICAL DATA

Plastic surface-mounted package with increased heatsink; 4 leads

SOT223



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Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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